**Preferred Device** 

# **High Voltage Transistors**

# **PNP Silicon**

## **Features**

• Pb-Free Package is Available

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	-300	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	-350	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-6.0	Vdc
Collector Current	I <sub>C</sub>	-1000	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C (Note 1)	P <sub>D</sub>	1.5	W
Storage Temperature Range	P <sub>D</sub>	-65 to +150	°C
Junction Temperature	TJ	150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	83.3	°C/W

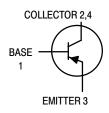
1. Device mounted on a glass epoxy printed circuit board 1.575 in x 1.575 in x 0.059 in; mounting pad for the collector lead min. 0.93 sq. in.



# ON Semiconductor®

http://onsemi.com

# PNP SILICON HIGH VOLTAGE TRANSISTOR SURFACE MOUNT



## MARKING DIAGRAM



TO-223 CASE 318E STYLE 1



BT2 = Specific Device Code D = Date

# ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
BSP16T1	TO-223	1000/Tape & Reel
BSP16T1G	TO-223 (Pb-Free)	1000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

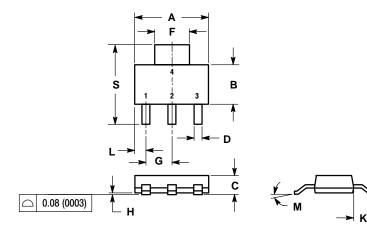
**Preferred** devices are recommended choices for future use and best overall value.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Characteristic	Symbol	IVIIII	IVIAX	Ullit
OFF CHARACTERISTICS				
Collector - Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	200		Vdc
$(I_C = -50 \text{ mAdc}, I_B = 0, L = 25 \text{ mH})$		-300	_	
Collector – Base Breakdown Voltage $(I_C = -100 \mu\text{Adc}, I_F = 0)$	V <sub>(BR)CBO</sub>	-300	_	Vdc
(0)				
Collector–Emitter Cutoff Current $(V_{CE} = -250 \text{ Vdc}, I_B = 0)$	ICES	_	-50	μAdc
Collector–Base Cutoff Current	I <sub>CBO</sub>			μAdc
$(V_{CB} = -280 \text{ Vdc}, I_{E} = 0)$		-	-1.0	
Emitter–Base Cutoff Current	I <sub>EBO</sub>			μAdc
$(V_{EB} = -6.0 \text{ Vdc}, I_{C} = 0)$		_	-20	
ON CHARACTERISTICS				
DC Current Gain	h <sub>FE</sub>			
$(V_{CE} = -10 \text{ Vdc}, I_C = -50 \text{ mAdc})$		30	120	_
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>			Vdc
$(I_C = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc})$		-	-2.0	
DYNAMIC CHARACTERISTICS				
Current Gain – Bandwidth Product	f <sub>T</sub>			MHz
$(V_{CE} = -10 \text{ Vdc}, I_{C} = -10 \text{ mAdc}, f = 30 \text{ MHz})$		15	-	
Collector-Base Capacitance	C <sub>obo</sub>			pF
$(V_{CB} = -10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$		_	15	

# **PACKAGE DIMENSIONS**

TO-223 (TO-261) CASE 318E-04 ISSUE K

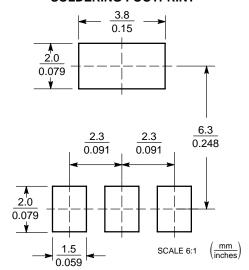


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

	INCHES MILL		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.249	0.263	6.30	6.70
В	0.130	0.145	3.30	3.70
С	0.060	0.068	1.50	1.75
D	0.024	0.035	0.60	0.89
F	0.115	0.126	2.90	3.20
G	0.087	0.094	2.20	2.40
Н	0.0008	0.0040	0.020	0.100
J	0.009	0.014	0.24	0.35
K	0.060	0.078	1.50	2.00
L	0.033	0.041	0.85	1.05
M	0 °	10 °	0 °	10 °
S	0.264	0.287	6.70	7.30

- STYLE 1:
  PIN 1. BASE
  2. COLLECTOR
  3. EMITTER
  4. COLLECTOR

# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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